

Electronic structure of Mn²⁺-doped phosphors

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Nanocrystalline materials doped with transition metal ions (Mn⁴⁺, Cr³⁺, Mn²⁺, Ni²⁺) are promising materials due to their potential application in many fields. In particular, nanocrystalline materials doped with Mn²⁺ ions have become the object of intensive research due to their practical application as a source of NIR phosphors. In the present work we report on results of a density functional theory study of geometric and electronic structures and optical transition energy of Mn²⁺-doped phosphors using various methods of calculations, in particular GGA-PBE, SCAN, HSE06. The geometric and electronic structures and optical transitions of the Mn²⁺ ion being in tetrahedral and octahedral environments are analyzed following the technique [1,2]. As an example, Figure 1 presents the results of GGA-PBE calculations of DOS of Mn²⁺-doped KMgF₃.

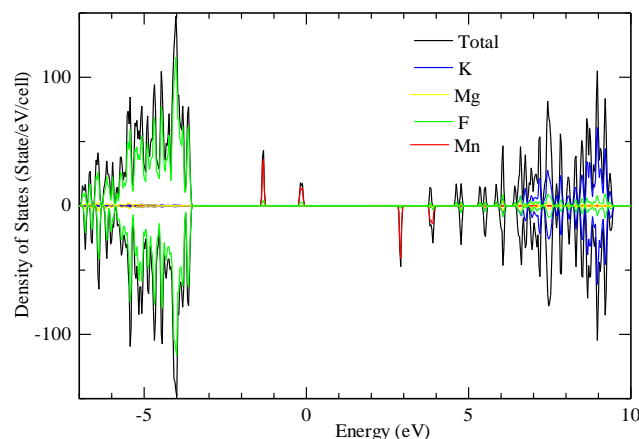


Figure 1. Density of states (DOS) of Mn²⁺ -doped KMgF₃.

[1] Umar Z., Khyzhun O., Yamamoto T., Brągiel P. (2024) Opt. Mater., 149, 115057.

[2] Umar Z., Kurboniyon M.S., et al. (2024) J. Lumin., 266, 120278.